

SKiiP® 2

## 2-pack - integrated intelligent Power System

### Power section

#### SKiiP 1602GB061-459CTV

### Features

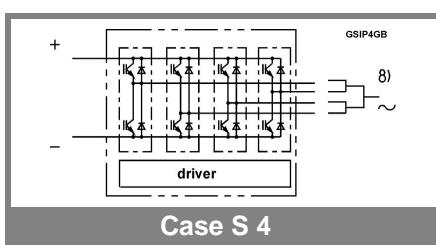
- SKiiP technology inside
- Low loss IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 2 power section)

- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 2) AC connection busbars must be connected by the user; copper busbars available on request

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	Values		Units
<b>IGBT</b>				
$V_{CES}$		600		V
$V_{CC}^1)$	Operating DC link voltage	400		V
$V_{GES}$		$\pm 20$		V
$I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	1600 (1200)		A
<b>Inverse diode</b>				
$I_F = -I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	1600 (1200)		A
$I_{FSM}$	$T_j = 150^\circ\text{C}$ , $t_p = 10 \text{ ms}$ ; sin.	16000		A
$I^2t$ (Diode)	Diode, $T_j = 150^\circ\text{C}$ , 10 ms	1280		kA²s
$T_{j1}(T_{stg})$		- 40 (- 25) ... + 150 (125)		°C
$V_{isol}$	AC, 1 min. (mainterminals to heat sink)	2500		V

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT</b>				
$V_{CEsat}$	$I_C = 1600 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,3 (2,6)	2,6	V
$V_{CEO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	0,8 (0,7)	1 (0,9)	V
$r_{CE}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	0,9 (1,2)	1 (1,3)	mΩ
$I_{CES}$	$V_{GE} = 0 \text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	(80)	1,6	mA
$E_{on} + E_{off}$	$I_C = 1600 \text{ A}$ , $V_{CC} = 300 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 400 \text{ V}$		144	mJ
			211	mJ
$R_{CC' + EE'}$	terminal chip, $T_j = 125^\circ\text{C}$	0,13		mΩ
$L_{CE}$	top, bottom	3,8		nH
$C_{CHC}$	per phase, AC-side	3,2		nF
<b>Inverse diode</b>				
$V_F = V_{EC}$	$I_F = 1600 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	1,5 (1,5)	1,8	V
$V_{TO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	0,8 (0,6)	1 (0,8)	V
$r_T$	$T_j = 25 \text{ (125)}^\circ\text{C}$	0,4 (0,5)	0,5 (0,6)	mΩ
$E_r$	$I_C = 1600 \text{ A}$ , $V_{CC} = 300 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 400 \text{ V}$	51		mJ
		61		mJ
<b>Mechanical data</b>				
$M_{dc}$	DC terminals, SI Units	6	8	Nm
$M_{ac}$	AC terminals, SI Units	13	15	Nm
w	SKiiP® 2 System w/o heat sink	3,5		kg
w	heat sink	8,5		kg
<b>Thermal characteristics (P 16 heat sink; 275 m³/h); "r" reference to temperature sensor</b>				
$R_{th(j-s)I}$	per IGBT		0,028	K/W
$R_{th(j-s)D}$	per diode		0,05	K/W
$R_{th(s-a)}$	per module		0,033	K/W
$Z_{th}$	$R_i$ (mK/W) (max. values)		$\tau_{ui}(s)$	
	1 2 3 4	1 2 3 4		
$Z_{th(j-r)I}$	3 21 3	1 0,13 0,001		
$Z_{th(j-r)D}$	6 39 6	1 0,13 0,001		
$Z_{th(r-a)}$	1,6 22 7 2,4	494 165 20 0,03		

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SKiiP® 2

## 2-pack - integrated intelligent Power System

### 2-pack integrated gate driver

### SKiiP 1602GB061-459CTV

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP® 2 gate driver)

<b>Absolute Maximum Ratings</b>		<b>Values</b>	<b>Units</b>
<b>Symbol</b>	<b>Conditions</b>		
$V_{S1}$	stabilized 15 V power supply	18	V
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_{iH}$	input signal voltage (high)	15 + 0,3	V
$dV/dt$	secondary to primary side	75	kV/ $\mu$ s
$V_{isolIO}$	input / output (AC, r.m.s., 2s )	2500	Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s )	1500	Vac
$f_{max}$	switching frequency	15	kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 25 ... + 85	°C

<b>Characteristics</b> ( $T_a = 25^\circ C$ )					
<b>Symbol</b>	<b>Conditions</b>	<b>min.</b>	<b>typ.</b>	<b>max.</b>	<b>Units</b>
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
$I_{S1}$	$V_{S1} = 15 V$	$290+470*f/f_{max}+1,3*(I_{AC}/A)$			mA
$I_{S2}$	$V_{S2} = 24 V$	$220+320*f/f_{max}+1,0*(I_{AC}/A)$			mA
$V_{iT+}$	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)			5,4	V
$R_{IN}$	input resistance		10		k $\Omega$
$t_{d(on)IO}$	input-output turn-on propagation time		1,1		$\mu$ s
$t_{d(off)IO}$	input-output turn-off propagation time		1,4		$\mu$ s
$t_{pERRRESET}$	error memory reset time	9			$\mu$ s
$t_{TD}$	top / bottom switch : interlock time		3,3		$\mu$ s
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)		1322		A
$I_{Vs1outmax}$	output current at pin 12/14		50		mA
$I_{AOmax}$	logic low output voltage		5		mA
$V_{O1}$	logic high output voltage		0,6		V
$V_{OH}$			30		V
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10 V$ )		1652		A
$I_{TRIPLG}$	ground fault protection				A
$T_{tp}$	over temperature protection	110		120	°C
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9 V$ ); (option)	400			V

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